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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Seung Wan CHAE et al.

Docket No.: 2336-257

Confirmation No. 2845

U.S. Patent Application No. 10/811,808

Group Art Unit: 2814

Filed: March 30, 2004

Examiner: Wai Sing Louie

or: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE

AND METHOD FOR MANUFACTURING THE SAME

SUPPLEMENTAL AMENDMENT

COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria VA 22313-1450

SIGNA

Sir:

Please do <u>NOT</u> enter the claim amendments presented in the Amendment filed *November* 18, 2005, which include a clerical error.

Please enter the following claim amendments which are consistent with the arguments presented in the Remarks section of the November 18, 2005 Amendment. The currently submitted claim amendments include markings showing changes relative to the original claims.

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